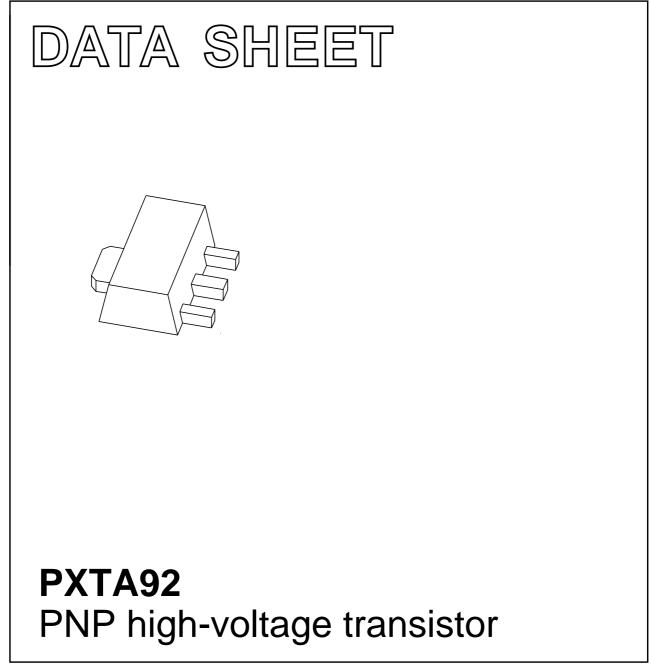
# DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 29 2004 Dec 09



HILIP

#### FEATURES

- Low current (max. 100 mA)
- High voltage (max. 300 V).

#### APPLICATIONS

• Telephony and professional communication equipment.

#### DESCRIPTION

PNP high-voltage transistor in a SOT89 plastic package. NPN complement: PXTA42.

#### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>	
PXTA92	*1N	

#### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.

\* = W: Made in China.

#### **ORDERING INFORMATION**

PIN	DESCRIPTION	
1	emitter	
2	collector	
3	base	

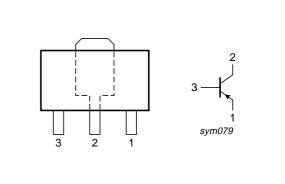


Fig.1 Simplified outline (SOT89) and symbol.

ITFE NUMBER	NAME DESCRIPTION VERSIO			
PXTA92	SC-62 plastic surface mounted package; collector pad for good heat SOT8 transfer; 3 leads		SOT89	

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-300	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-300	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current (DC)		-	-100	mA
I <sub>CM</sub>	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	-	1.3	W
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>. For other mounting conditions, see *"Thermal considerations for SOT89 in the General Part of associated Handbook"*.

### **PXTA92**

PXTA92

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	96	K/W
R <sub>th(j-s)</sub>	thermal resistance from junction to soldering point		16	K/W

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>. For other mounting conditions, see *"Thermal considerations for SOT89 in the General Part of associated Handbook"*.

#### CHARACTERISTICS

 $T_{amb}$  = 25 °C unless otherwise specified.

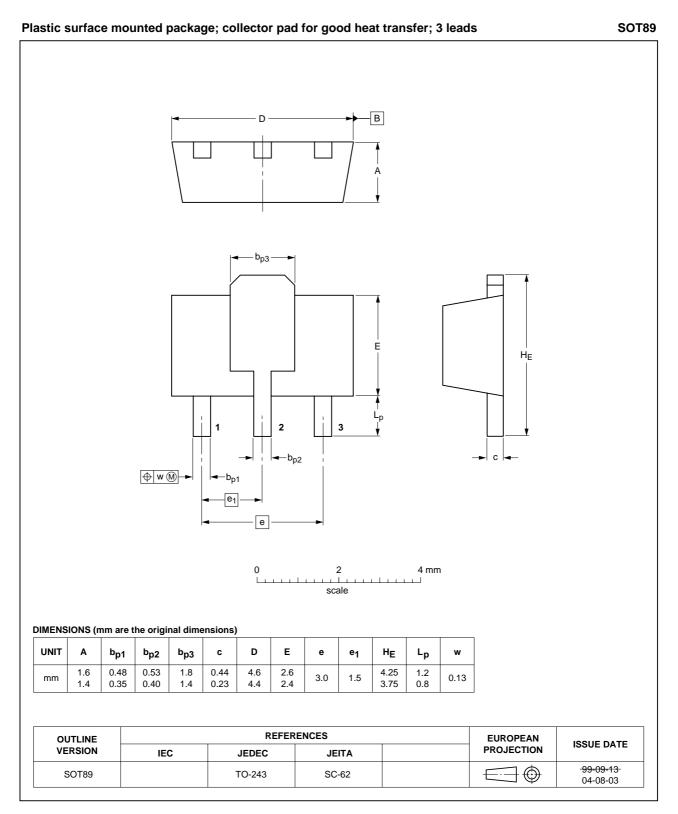
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$I_E = 0 \text{ A}; V_{CB} = -200 \text{ V}$	-	-250	nA
I <sub>EBO</sub>	emitter-base cut-off current	$I_{C} = 0 \text{ A}; V_{BE} = -3 \text{ V}$	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -10 V; note 1			
		$I_{\rm C} = -1  \rm mA$	25	-	
		$I_{\rm C} = -10  {\rm mA}$	40	-	
		I <sub>C</sub> = -30 mA	25	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = -20 \text{ mA}; I_{\rm B} = -2 \text{ mA}$	-	-500	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{\rm C} = -20 \text{ mA}; I_{\rm B} = -2 \text{ mA}$		-900	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = -20 \text{ V};$ f = 1 MHz	-	6	pF
f <sub>T</sub>	transition frequency	$I_{C} = -10 \text{ mA}; V_{CE} = -20 \text{ V};$ f = 100 MHz	50	_	MHz

#### Note

1. Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ .

### PXTA92

#### PACKAGE OUTLINE



PXTA92

#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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